

# NX6352GP Series

LASER DIODE

1 270/1 290/1 310/1 330/1 350 nm AlGaInAs MQW-DFB LASER DIODE

FOR 9.8 Gb/s CPRI and 10G E-PON ONU APPLICATION

R08DS0088EJ0100

Rev.1.00

Feb 25, 2013

## DESCRIPTION

The NX6352GP series is a 1 270/1 290/1 310/1 330/1 350 nm Multiple Quantum Well (MQW) structured Distributed Feed-Back (DFB) laser diode with InGaAs monitor PIN-PD.

## APPLICATIONS

- 9.8 Gbps CPRI
- 10G E-PON ONU

## FEATURES

- Optical output power
- Low threshold current
- Differential efficiency
- Wide operating temperature range
- InGaAs monitor PIN-PD
- CAN package
- Focal point

$P_O = 8.5 \text{ mW}$

$I_{th} = 7 \text{ mA}$

$\eta_d = 0.35 \text{ W/A}$

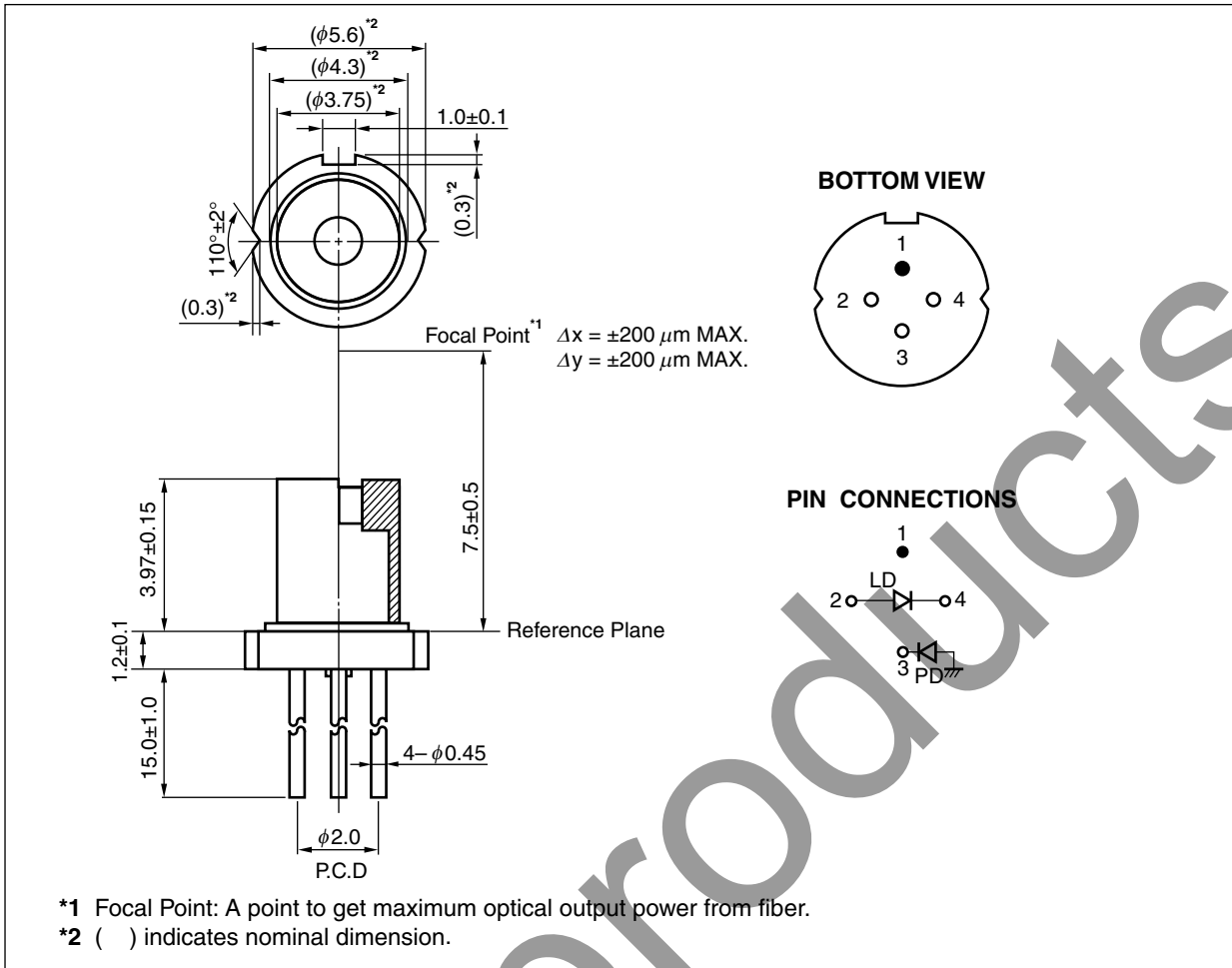
$T_C = -40 \text{ to } +85^\circ\text{C}$

$\phi 5.6 \text{ mm}$

7.5 mm



PACKAGE DIMENSIONS (UNIT: mm)



**ORDERING INFORMATION**

Part Number	Package	Pin Connections
NX6352GPxx <sup>*1</sup>	4-pin CAN with aspherical lens cap	

**Note: 1.** The last two digits (“xx”) of Part Number indicates Wavelength Code.  
The relationships between the code and wavelength are as follows.

WAVELENGTH CODE	WAVELENGTH (nm)
27	1 270
29	1 290
31	1 310
33	1 330
35	1 350

- Remarks**
1. The color of lens cap might be observed differently.
  2. The hermetic test will be performed as AQL 1.0%.

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**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C, unless otherwise specified)**

Parameter	Symbol	Ratings	Unit
Optical Output Power	P <sub>O</sub>	15	mW
Forward Current of LD	I <sub>F</sub>	120	mA
Reverse Voltage of LD	V <sub>R</sub>	2.0	V
Forward Current of PD	I <sub>F</sub>	10.0	mA
Reverse Voltage of PD	V <sub>R</sub>	15	V
Operating Case Temperature	T <sub>C</sub>	-40 to +85	°C
Storage Temperature	T <sub>stg</sub>	-40 to +95	°C
Lead Soldering Temperature	T <sub>slid</sub>	350 (3 sec.)	°C
Relative Humidity (noncondensing)	RH	85	%

**RECOMMENDED LD DRIVE CURRENT AT MODULE LEVEL**

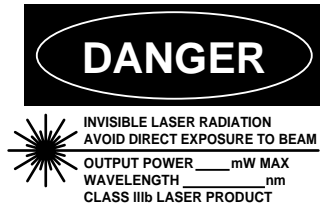
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Bias Current	I <sub>bias</sub>	T <sub>C</sub> = 25°C	-	30	-	mA
		T <sub>C</sub> = 85°C	-	-	70	

**ELECTRO-OPTICAL CHARACTERISTICS  
(T<sub>C</sub> = -40 to +85°C, CW, BOL, unless otherwise specified)**

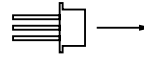
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Signaling Rate			-	9.8304	-	Gb/s	
Optical Output Power	P <sub>O</sub>		-	8.5	-	mW	
Operating Voltage	V <sub>op</sub>	P <sub>O</sub> = 8.5 mW	-	-	2.0	V	
Threshold Current	I <sub>th</sub>	T <sub>C</sub> = 25°C	-	7	15	mA	
			-	-	30		
Differential Efficiency	η <sub>d</sub>	P <sub>O</sub> = 8.5 mW, T <sub>C</sub> = 25°C	0.23	-	-	W/A	
		P <sub>O</sub> = 8.5 mW	0.13	-	-		
Peak Emission Wavelength	λ <sub>p</sub>	P <sub>O</sub> = 8.5 mW	NX6352GP27	1 260	-	1 280	nm
			NX6352GP29	1 280	-	1 300	
			NX6352GP31	1 300	-	1 320	
			NX6352GP33	1 320	-	1 340	
			NX6352GP35	1 340	-	1 360	
Side Mode Suppression Ratio	SMSR	P <sub>O</sub> = 8.5 mW	35	-	-	dB	
Rise Time	t <sub>r</sub>	20-80% *1	-	-	50	ps	
Fall Time	t <sub>f</sub>	80-20% *1	-	-	50	ps	
Monitor Current	I <sub>m</sub>	V <sub>R</sub> = 1.5 V, P <sub>O</sub> = 8.5 mW	100	-	1 000	μA	
Monitor Dark Current	I <sub>D</sub>	V <sub>R</sub> = 3.3 V, T <sub>C</sub> = 25°C	-	-	10	nA	
		V <sub>R</sub> = 3.3 V	-	-	100		
Monitor PD Terminal Capacitance	C <sub>t</sub>	V <sub>R</sub> = 3.3 V, f = 1 MHz	-	-	20	pF	

**Note:** 1. 9.8304 Gb/s, PRBS 2<sup>31</sup> -1, NRZ, Duty Cycle = 50%

**SAFETY INFORMATION ON THIS PRODUCT**



**SEMICONDUCTOR LASER**



**AVOID EXPOSURE-Invisible**  
Laser Radiation is emitted from  
this aperture

<p><b>Warning</b> Laser Beam</p>	<p>A laser beam is emitted from this diode during operation. The laser beam, visible or invisible, directly or indirectly, may cause injury to the eye or loss of eyesight.</p> <ul style="list-style-type: none"> <li>• Do not look directly into the laser beam.</li> <li>• Avoid exposure to the laser beam, any reflected or collimated beam.</li> </ul>
<p><b>Caution</b> GaAs Products</p>	<p>This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.</p> <ul style="list-style-type: none"> <li>• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.             <ol style="list-style-type: none"> <li>1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.</li> <li>2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.</li> </ol> </li> <li>• Do not burn, destroy, cut, crush, or chemically dissolve the product.</li> <li>• Do not lick the product or in any way allow it to enter the mouth.</li> </ul>

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<b>Revision History</b>	<b>NX6352GP Series Data Sheet</b>
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Rev.	Date	Description	
		Page	Summary
1.00	Feb 25, 2013	-	First edition issued

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